

Docket No.: T2171.0180/P180

(PATENT)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Takahisa Yamaha

Application No.: 09/518,709

Group Art Unit: 2815

Filed: March 3, 2000

Examiner: E. Ortiz

For: MANUFACTURE METHOD FOR SEMICONDUCTOR WITH SMALL

VARIATION IN MOS THRESHOLD

VOLTAGE

<u>AMENDMENT</u>

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Commissioner for Patents Washington, DC 20231

Dear Sir:

In response to the Office Action dated November 7, 2001, please amend the above-identified U.S. patent application as follows:

## In the Claims

Please cancel claims 1-13 without prejudice.

Please add new claims 22-28 pursuant to 37 C.F.R. § 1.121(c)(i) as set forth in the "clean" version set forth below. Entry is respectfully requested. A version with markings to show the changes made pursuant to 37 C.F.R. § 1.121(c)(1)(ii) is attached hereto as Appendix A.

\_\_\_\_ If check, the optional complete set of "clean" claims pursuant to 37 C.F.R. § 1.121(c)(3) is attached hereto as Appendix B.